# UNISONIC TECHNOLOGIES CO., LTD

**BD135** 

**Preliminary** 

NPN EPITAXIAL SILICON TRANSISTOR

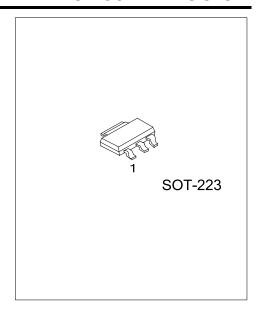
# NPN EPITAXIAL TRANSISTOR

#### ■ DESCRIPTION

The UTC **BD135** is an NPN epitaxial transistor; it uses UTC's advanced technology to provide the customers with high DC current gain, etc.

#### **■ FEATURES**

\* high DC current gain



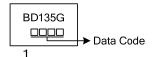
### **■ ORDERING INFORMATION**

Ordering Number	Dealtess	Pin	Assignm	Doolsing	
Ordering Number	Package	1	2	3	Packing
BD135G-xx-AA3-R	SOT-223	В	С	Е	Tape Reel

Note: Pin Assignment: B: Base C: Collector E: Emitter

BD135G-xx-AA3-R
(1)Packing Type
(1) R: Tape Reel, K: Bulk
(2) AA3: SOT-223, T60: TO-126
(3) Rank
(3) refer to CLASSIFICATION OF h<sub>FE3</sub>
(4) G: Halogen Free and Lead Free, L: Lead Free

#### **■ MARKING**



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# ABSOLUTE MAXIMUM RATINGS (T<sub>C</sub>=25°C unless otherwise noted)

PARAMETER	SYMBOL	RATINGS	UNIT
Collector-Base Voltage	$V_{CBO}$	45	V
Collector-Emitter Voltage	$V_{CEO}$	45	V
Emitter-Base Voltage	$V_{EBO}$	5	V
Collector Current (DC)	Ic	1.5	Α
Collector Current (Pulse)	I <sub>CP</sub>	3.0	Α
Base Current	I <sub>B</sub>	0.5	Α
Collector Power Dissipation	Pc	12.5	W
Junction Temperature	TJ	150	°C
Storage Temperature	T <sub>STG</sub>	-55 ~150	°C

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

### ELECTRICAL CHARACTERISTICS (T<sub>C</sub> =25°C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Collector-Emitter Saturation Voltage	$V_{CEO(SUS)}$	I <sub>C</sub> =30mA, I <sub>B</sub> =0	45			V
Collector Cut-Off Current	I <sub>CBO</sub>	$V_{CB}$ =30 $V$ , $I_E$ =0			0.1	μA
Emitter Cut-Off Current	I <sub>EBO</sub>	V <sub>EB</sub> =5V, I <sub>C</sub> =0			10	μΑ
	h <sub>FE1</sub>	V <sub>CE</sub> =2V, I <sub>C</sub> =5mA	25			
DC Current Gain	h <sub>FE2</sub>	V <sub>CE</sub> =2V, I <sub>C</sub> =0.5A	25			
	h <sub>FE3</sub>	V <sub>CE</sub> =2V, I <sub>C</sub> =150mA	40		250	
Collector-Emitter Saturation Voltage	V <sub>CE(SAT)</sub>	I <sub>C</sub> =500mA, I <sub>B</sub> =50mA			0.5	V
Base-Emitter ON Voltage	$V_{BE\_ON}$	V <sub>CE</sub> =2V, I <sub>C</sub> =0.5A			1	V

Note: Pulse Test: Pulse Width ≤ 300µS, Duty Cycle ≤ 2%.

## **h**<sub>FE3</sub> CLASSIFICATION

CLASSIFICATION	6	10	16		
h⊑⊑₃	40 ~ 100	63 ~ 160	100 ~ 250		



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